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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/820,476	04/08/2004	Peter J. Hopper	Peter J. Hopper 100-18110 (P05269-D01)	
33402	7590 10/31/2005	EXAMINER		
	CES OF MARK C. PIO	NGUYEN, TUAN H		
P.O. BOX 300 PETALUMA, CA 94953			ART UNIT	PAPER NUMBER
			2813	

DATE MAILED: 10/31/2005

Please find below and/or attached an Office communication concerning this application or proceeding.

		<del>, -</del>			- New			
Office Action Summary		Application	No.	Applicant(s)	X			
		10/820,476		HOPPER ET AL.				
		Examiner		Art Unit				
		Tuan H. Ngu	·	2813				
The MAILING DATE of this communication appears on the cover sheet with the correspondence address Period for Reply								
A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) OR THIRTY (30) DAYS, WHICHEVER IS LONGER, FROM THE MAILING DATE OF THIS COMMUNICATION.  - Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.  - If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.  - Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).								
Status								
1)⊠	Responsive to communication(s) filed on 23 Au	<u>ugust 2005</u> .						
,—	This action is <b>FINAL</b> . 2b)⊠ This action is non-final.							
3)□	Since this application is in condition for allowance except for formal matters, prosecution as to the merits is							
	closed in accordance with the practice under Ex parte Quayle, 1935 C.D. 11, 453 O.G. 213.							
Disposition of Claims								
4)⊠	Claim(s) 7-13 and 17-27 is/are pending in the a	application.						
	4a) Of the above claim(s) is/are withdrawn from consideration.							
5)🖾	Claim(s) <u>7-13</u> is/are allowed.							
•	Claim(s) <u>17,19 and 27</u> is/are rejected.							
-	Claim(s) 18 and 20-26 is/are objected to.							
8)[_]	Claim(s) are subject to restriction and/or	r election req	Jirement.					
Applicat	ion Papers							
9)[	The specification is objected to by the Examine	er.						
10) The drawing(s) filed on is/are: a) □ accepted or b) □ objected to by the Examiner.								
	Applicant may not request that any objection to the		•		. 4 40471			
Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).								
11) The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.								
Priority (	under 35 U.S.C. § 119							
12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).  a) All b) Some * c) None of:								
	<ul> <li>1. Certified copies of the priority documents have been received.</li> <li>2. Certified copies of the priority documents have been received in Application No</li> </ul>							
3. Copies of the certified copies of the priority documents have been received in this National Stage								
application from the International Bureau (PCT Rule 17.2(a)).								
* See the attached detailed Office action for a list of the certified copies not received.								
Attachmer	nt(s)							
1) Notice of References Cited (PTO-892)  4) Interview Summary (PTO-413)								
2) Notice of Draftsperson's Patent Drawing Review (PTO-948) 3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08) Paper No(s)/Mail Date 9/12/05.								
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### **DETAILED ACTION**

#### Continued Examination Under 37 CFR 1.114

A request for continued examination under 37 CFR 1.114, including the fee set forth in 37 CFR 1.17(e), was filed in this application after final rejection. Since this application is eligible for continued examination under 37 CFR 1.114, and the fee set forth in 37 CFR 1.17(e) has been timely paid, the finality of the previous Office action has been withdrawn pursuant to 37 CFR 1.114. Applicant's submission filed on 8/23/05 has been entered.

## Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.

Claims 17, 19, 27 are rejected under 35 U.S.C. 102(e) as being anticipated by U.S. Pat. No. 6,413,832 to Wu et al. (cited ref.).

Wu et al., figs. 1-5 and text on col. 3-4 teaches the claimed method for forming a semiconductor device on an insulation region including: forming a trench 24 in the insulation region 12, 14, 16, the trench 24 having a side wall surface and a bottom surface, the side wall surface extending continuously from the top surface to the bottom surface and exposing only the insulation region 12 (fig. 3); forming a layer 32 of

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conductive material on the insulation region 12 to contact the trench; etching the layer 32 of conductive material to form an opening and a conductive spacer that contacts the side wall surface; and forming a layer 42 of isolation material on the insulation region 12 and conductive spacer 32 to contact the opening (fig. 4, col. 3, last paragraph to col. 4, first paragraph).

With respect to claims 19, 21, fig. 5 shows the step of etching the layer of isolation material to form a hole, exposed bottom surface of the trench, and an isolation spacer 42 that contacts a side wall of the conductive spacer 32; and forming a layer of conductive material on the insulation region 12,the conductive spacer 32, and the isolation spacer 42 to contact the hole (fig. 5).

# Allowable Subject Matter

Claims 7-13 are allowed.

Claims 18, 20-26 are objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

The following is a statement of reasons for the indication of allowable subject matter: None of the references of record teaches or suggests the claimed method form forming a semiconductor device including the step of forming a conductive region making an electrical connection with the first conductive spacer as recited in claim 7, 18, 20, 23-26; or forming a layer of insulation material on the interior spacer to contact the aperture as recited in claims 21, 22.

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Any inquiry concerning this communication or earlier communications from the examiner should be directed to Tuan H. Nguyen whose telephone number is 571-272-1694. The examiner can normally be reached on 9AM-5:30PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Carl Whitehead Jr. can be reached on 571-272-1702. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Man H- Nguyen Tuan H. Nguyen Primary Examiner Art Unit 2813